

CMOS Digital Integrated Circuits Silicon Monolithic

## TC7WZ125FU

#### 1. Functional Description

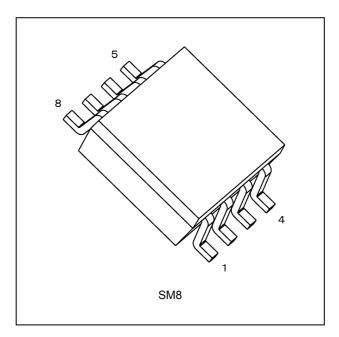
· Dual Bus Buffer with 3-State Output

## 2. Features

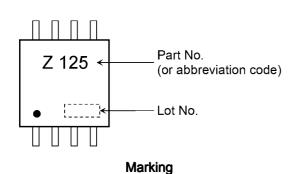
- (1) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C (Note 1)
- (2) High output current:  $\pm 24$  mA (min) at  $V_{CC} = 3.0$  V
- (3) Super high speed operation:  $t_{pd} = 2.6$  ns (typ.) at  $V_{CC} = 5.0$  V,  $C_L = 50$  pF
- (4) Operation voltage range:  $V_{CC} = 1.65$  to 5.5 V
- (5) 5.5 V tolerant inputs
- (6) 5.5 V power down protection output
- (7) Matches the performance of TC74LCX series when operated at 3.3 V  $V_{\rm CC}$

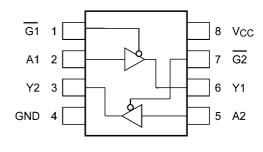
Note 1: For devices with the ordering part number ending in J(CT.  $T_{opr}$  = -40 to 85 °C for the other devices.

## 3. Packaging



### 4. Marking and Pin Assignment





Pin Assignment (Top view)

Start of commercial production

2020-01



### 5. IEC Logic Symbol



#### 6. Truth Table

Input A	Input G	Output Y
Х	Н	Z
L	L	L
Н	L	Н

X: Don't care

Z: High impedance

## 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 6.0	V
Input voltage	$V_{IN}$		-0.5 to 6.0	V
DC output voltage	$V_{OUT}$	(Note 1)	-0.5 to 6.0	V
		(Note 2)	-0.5 to V <sub>CC</sub> + 0.5	
Input diode current	I <sub>IK</sub>		-20	mA
Output diode current	I <sub>OK</sub>	(Note 3)	-20	mA
DC output current	I <sub>OUT</sub>		±50	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±50	mA
Power dissipation	$P_D$		300	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC} = 0 \text{ V}$  or high impedance condition

Note 2: High (H) or Low (L) state. I<sub>OUT</sub> absolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND



## 8. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V <sub>CC</sub>		_	1.65 to 5.5	V
		(Note 1)	_	1.5 to 5.5	
Input voltage	V <sub>IN</sub>		_	0 to 5.5	V
Output voltage	V <sub>OUT</sub>	(Note 2)	_	0 to 5.5	V
		(Note 3)	_	0 to V <sub>CC</sub>	
Operating temperature	T <sub>opr</sub>	(Note 4)	_	-40 to 125	°C
		(Note 5)	_	-40 to 85	
Input rise and fall time	dt/dv		$V_{CC}$ = 1.8 ± 0.15 V, 2.5 ± 0.2 V	0 to 20	ns/V
			V <sub>CC</sub> = 3.3 ± 0.3 V	0 to 10	
			V <sub>CC</sub> = 5.0 ± 0.5 V	0 to 5	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: Data retention only

Note 2:  $V_{CC}$  = 0 V or high impedance condition

Note 3: High (H) or Low (L) state.

Note 4: For devices with the ordering part number ending in J(CT.

Note 5: For devices except those with the ordering part number ending in J(CT.

#### 9. Electrical Characteristics

## 9.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		1.65 to 1.95	V <sub>CC</sub> × 0.75	_	_	V
				2.3 to 5.5	$V_{CC} \times 0.70$	1		
Low-level input voltage	V <sub>IL</sub>	_		1.65 to 1.95	_	-	$V_{CC} \times 0.25$	V
				2.3 to 5.5	_	_	$V_{CC} \times 0.30$	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OH</sub> = -100 μA	1.65	1.55	1.65		V
				2.3	2.2	2.3	-	
				3.0	2.9	3.0	_	
				4.5	4.4	4.5		
			I <sub>OH</sub> = -4 mA	1.65	1.29	1.52	1	
			I <sub>OH</sub> = -8 mA	2.3	1.9	2.15	_	
			I <sub>OH</sub> = -16 mA	3.0	2.4	2.8	1	
			I <sub>OH</sub> = -24 mA	3.0	2.3	2.68	1	
			I <sub>OH</sub> = -32 mA	4.5	3.8	4.2	1	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IL}$	I <sub>OL</sub> = 100 μA	1.65	_	0.0	0.1	<b>\</b>
				2.3	_	0.0	0.1	
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I <sub>OL</sub> = 4 mA	1.65	_	0.08	0.24	
			$I_{OL}$ = 8 mA	2.3	_	0.1	0.3	
			I <sub>OL</sub> = 16 mA	3.0	_	0.15	0.4	
			I <sub>OL</sub> = 24 mA	3.0	_	0.22	0.55	
			I <sub>OL</sub> = 32 mA	4.5	_	0.22	0.55	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_		±1	μА
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.65 to 5.5	_		±1	μА
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V		0	_		1	μА
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = 5.5 V or GND		1.65 to 5.5	_	_	1	μА



## 9.2. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

Characteristics	Symbol	Test Conditio	n	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		1.65 to 1.95	V <sub>CC</sub> × 0.75	_	V
				2.3 to 5.5	V <sub>CC</sub> × 0.70	_	
Low-level input voltage	V <sub>IL</sub>	_		1.65 to 1.95	_	V <sub>CC</sub> × 0.25	V
				2.3 to 5.5	_	$V_{CC} \times 0.30$	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OH</sub> = -100 μA	1.65	1.55	_	٧
				2.3	2.2	_	
				3.0	2.9	_	
				4.5	4.4	_	
			I <sub>OH</sub> = -4 mA	1.65	1.29	_	
			I <sub>OH</sub> = -8 mA	2.3	1.9	_	
			I <sub>OH</sub> = -16 mA	3.0	2.4	_	
			I <sub>OH</sub> = -24 mA	3.0	2.3	_	
			I <sub>OH</sub> = -32 mA	4.5	3.8	_	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IL}$	I <sub>OL</sub> = 100 μA	1.65	_	0.1	V
				2.3	_	0.1	
				3.0	_	0.1	
				4.5		0.1	
			I <sub>OL</sub> = 4 mA	1.65	_	0.24	
			I <sub>OL</sub> = 8 mA	2.3		0.3	
			I <sub>OL</sub> = 16 mA	3.0		0.4	
			I <sub>OL</sub> = 24 mA	3.0	_	0.55	
			I <sub>OL</sub> = 32 mA	4.5		0.55	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±10	μΑ
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.65 to 5.5	_	±10	μА
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V		0		10	μΑ
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = 5.5 V or GND		1.65 to 5.5	_	10	μΑ



## 9.3. DC Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C)

Characteristics	Symbol	Test Condition	n	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		1.65 to 1.95	V <sub>CC</sub> × 0.75	_	V
				2.3 to 5.5	$V_{CC} \times 0.70$	_	
Low-level input voltage	V <sub>IL</sub>	_		1.65 to 1.95	_	V <sub>CC</sub> × 0.25	V
				2.3 to 5.5	_	$V_{CC} \times 0.30$	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	1.65	1.55	_	V
				2.3	2.2	_	
				3.0	2.9	_	
				4.5	4.4	_	
			I <sub>OH</sub> = -4 mA	1.65	0.95	_	
			I <sub>OH</sub> = -8 mA	2.3	1.7	_	
			I <sub>OH</sub> = -16 mA	3.0	2.2	_	
			I <sub>OH</sub> = -24 mA	3.0	2.0	_	
			I <sub>OH</sub> = -32 mA	4.5	3.4	_	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IL}$	I <sub>OL</sub> = 100 μA	1.65	_	0.1	V
				2.3	_	0.1	
				3.0	_	0.1	
				4.5	_	0.1	
			I <sub>OL</sub> = 4 mA	1.65	_	0.7	
			I <sub>OL</sub> = 8 mA	2.3	_	0.45	
			I <sub>OL</sub> = 16 mA	3.0	_	0.6	
			I <sub>OL</sub> = 24 mA	3.0	_	0.8	
			I <sub>OL</sub> = 32 mA	4.5	_	0.8	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±20	μΑ
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.65 to 5.5	_	±20	μА
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V		0	_	100	μΑ
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = 5.5 V or GND		1.65 to 5.5	_	100	μА

Note: For devices with the ordering part number ending in J(CT.



## 9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Propagation delay time	$t_{PLH}, t_{PHL}$		$R_L = 1 M\Omega$	$1.8 \pm 0.15$	15	2.0	5.3	11.0	ns
			See 9.5 AC Test Circuit, Table 9.5.1	2.5 ± 0.2		0.8	3.4	7.5	
			Circuit, Table 9.5.1	$3.3 \pm 0.3$		0.5	2.5	5.2	
				5.0 ± 0.5		0.5	2.1	4.5	
			$R_L = 500 \Omega$	$3.3 \pm 0.3$	50	1.5	3.2	5.7	ns
			See 9.5 AC Test Circuit, Table 9.5.1	5.0 ± 0.5		0.8	2.6	5.0	
Output enable time	$t_{PZL}, t_{PZH}$		R <sub>L</sub> = 500 Ω	$1.8 \pm 0.15$	50	2.0	7.0	14.9	ns
			See 9.5 AC Test Circuit, Table 9.5.1	2.5 ± 0.2		1.5	4.6	8.5	
			Circuit, Table 9.5.1	$3.3 \pm 0.3$		1.5	3.5	6.2	
				5.0 ± 0.5		8.0	2.8	5.5	
Output disable time	$t_{PLZ}, t_{PHZ}$		R <sub>L</sub> = 500 Ω	$1.8 \pm 0.15$	50	2.0	5.4	11.8	ns
			See 9.5 AC Test Circuit, Table 9.5.1	$2.5 \pm 0.2$		1.5	4.0	8.0	
			Circuit, Table 9.5.1	$3.3 \pm 0.3$		1.0	3.5	5.7	
				5.0 ± 0.5		0.5	2.5	4.7	
Input capacitance	C <sub>IN</sub>		_	0 to 5.5	_	_	4	_	pF
Output capacitance	C <sub>OUT</sub>		_	0 to 5.5	_	_	4		pF
Power dissipation	C <sub>PD</sub>	(Note 1)	_	3.3	_	_	17	_	pF
capacitance				5.5		_	24	_	

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per 1 bit)}$ 

## 9.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit								
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	$R_L = 1 M\Omega$	$1.8 \pm 0.15$	15	2.0	11.5	ns								
		See 9.5 AC Test Circuit, Table 9.5.1	$2.5 \pm 0.2$		8.0	8.0									
		Table 9.5.1	$3.3 \pm 0.3$		0.5	5.5									
			$5.0 \pm 0.5$		0.5	4.8									
		$R_L = 500 \Omega$	$3.3 \pm 0.3$	50	1.5	6.0	ns								
		See 9.5 AC Test Circuit, Table 9.5.1	$5.0 \pm 0.5$		8.0	5.3									
Output enable time	$\begin{array}{c} t_{PZL}, t_{PZH} \\ R_L = 500 \; \Omega \\ \text{See } 9.5 \; \text{AC Test Circuit} \\ \text{Table } 9.5.1 \end{array}$	-	$1.8 \pm 0.15$	50	2.0	16.6	ns								
		· 1	$2.5\pm0.2$		1.5	9.0									
									Table 9.5.1	Table 9.5.1	Table 9.5.1	$3.3 \pm 0.3$		1.5	6.5
			$5.0 \pm 0.5$		8.0	5.8									
Output disable time	$t_{PLZ}, t_{PHZ}$	R <sub>L</sub> = 500 Ω	$1.8\pm0.15$	50	2.0	12.7	ns								
				See 9.5 AC Test Circuit, Table 9.5.1	· · · · · · · · · · · · · · · · · · ·	$2.5\pm0.2$		1.5	8.5						
		Table 5.5.1	$3.3 \pm 0.3$		1.0	6.0									
			$5.0 \pm 0.5$		0.5	5.0									



# 9.6. AC Characteristics (Note) (Unless otherwise specified, $T_a$ = -40 to 125 °C, Input: $t_r$ = $t_f$ = 3 ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit		
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	$R_L = 1 M\Omega$	1.8 ± 0.15	15	2.0	13.0	ns		
		See 9.7 AC Test Circuit, Table 9.7.1	$2.5\pm0.2$		0.8	9.0			
		Table 9.7.1	$3.3 \pm 0.3$		0.5	6.5			
			$5.0 \pm 0.5$		0.5	5.5			
		$R_L$ = 500 $Ω$ See 9.7 AC Test Circuit,	$3.3 \pm 0.3$	50	1.5	7.0	ns		
		Table 9.7.1	$5.0 \pm 0.5$		0.8	6.0			
Output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>	R <sub>L</sub> = 500 Ω	$1.8 \pm 0.15$	50	2.0	18.5	ns		
		See 9.7 AC Test Circuit, Table 9.7.1	1 ' 1	· · · · · · · · · · · · · · · · · · ·	$2.5 \pm 0.2$		1.5	10.0	
				$3.3 \pm 0.3$		1.5	7.5	]	
			$5.0 \pm 0.5$		0.8	6.5			
Output disable time	$t_{PLZ}, t_{PHZ}$	R <sub>L</sub> = 500 Ω	1.8 ± 0.15	50	2.0	14.0	ns		
		See 9.7 AC Test Circuit, Table 9.7.1	$2.5\pm0.2$		1.5	9.5	]		
		Table 9.7.1	$3.3 \pm 0.3$		1.0	7.0			
			$5.0 \pm 0.5$		0.5	5.5			

Note: For devices with the ordering part number ending in J(CT.

#### 9.7. AC Test Circuit

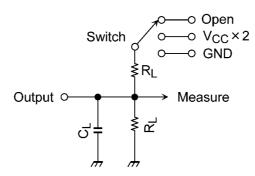


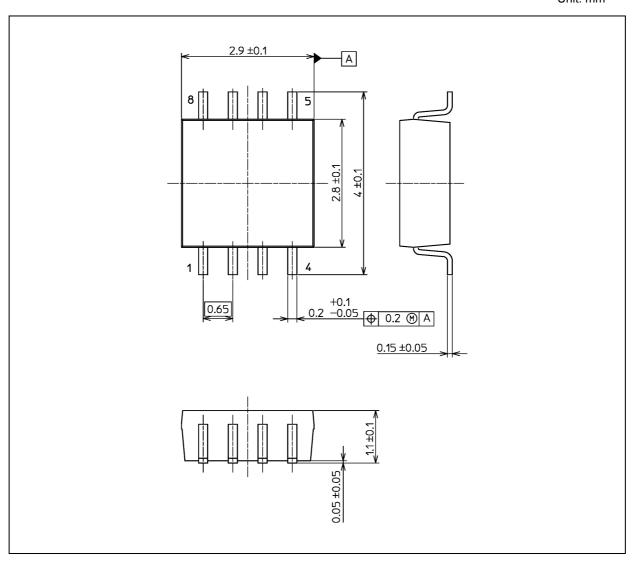
Table 9.5.1 Parameter for AC Test Circuit

Characteristics	Switch
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
t <sub>PLZ</sub> , t <sub>PZL</sub>	V <sub>CC</sub> × 2
t <sub>PHZ</sub> , t <sub>PZH</sub>	GND



## **Package Dimensions**

Unit: mm



Weight: 21 mg (typ.)

	Package Name(s)
JEDEC: SOT-505	
Nickname: SM8	



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